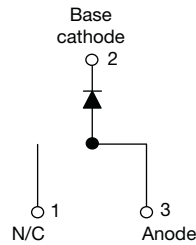


## High Performance Schottky Rectifier, 10 A


 TO-263AB (D<sup>2</sup>PAK)


### FEATURES

- 150 °C T<sub>J</sub> operation
- TO-220 and D<sup>2</sup>PAK packages
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
 COMPLIANT  
 HALOGEN  
**FREE**

### PRODUCT SUMMARY

Package	TO-263AB (D <sup>2</sup> PAK)
I <sub>F(AV)</sub>	10 A
V <sub>R</sub>	35 V, 45 V
V <sub>F</sub> at I <sub>F</sub>	0.57 V
I <sub>RM</sub> max.	15 mA at 125 °C
T <sub>J</sub> max.	150 °C
Diode variation	Single die
E <sub>AS</sub>	8.0 mJ

### DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

### MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
I <sub>F(AV)</sub>	Rectangular waveform	10	A
I <sub>FRM</sub>	T <sub>C</sub> = 135 °C	20	
V <sub>RRM</sub>		35, 45	V
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1060	A
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V
T <sub>J</sub>	Range	-65 to +150	°C

### VOLTAGE RATINGS

PARAMETER	SYMBOL	VS-MBRB1035PbF	VS-MBRB1045PbF	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	35	45	V
Maximum working peak reverse voltage	V <sub>RWM</sub>			

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 135 °C, rated V <sub>R</sub>	10	A
Peak repetitive forward current	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 135 °C	20	
Non-repetitive surge current	I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	1060	
		Surge applied at rated load conditions halfwave, single phase, 60 Hz	150	
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 A, L = 4 mH	8	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 μs Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical	2	A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}^{(1)}$	20 A	$T_J = 25\text{ }^\circ\text{C}$	0.84	V
		10 A	$T_J = 125\text{ }^\circ\text{C}$	0.57	
		20 A		0.72	
Maximum instantaneous reverse current	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	Rated DC voltage	0.1	mA
		$T_J = 125\text{ }^\circ\text{C}$		15	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J$ maximum		0.354	V
Forward slope resistance	$r_t$			17.6	m $\Omega$
Maximum junction capacitance	$C_T$	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 $^\circ\text{C}$		600	pF
Typical series inductance	$L_S$	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated $V_R$		10 000	V/ $\mu\text{s}$

Note

(1) Pulse width < 300  $\mu\text{s}$ , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction temperature range	$T_J$			-65 to +150	$^\circ\text{C}$
Maximum storage temperature range	$T_{Stg}$			-65 to +175	
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation		2.0	$^\circ\text{C/W}$
Typical thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, smooth and greased (Only for TO-220)		0.50	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device		Case style D <sup>2</sup> PAK		MBRB1035	
				MBRB1045	

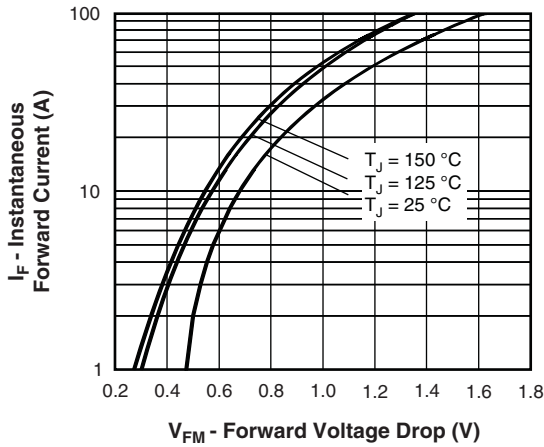


Fig. 1 - Maximum Forward Voltage Drop Characteristics

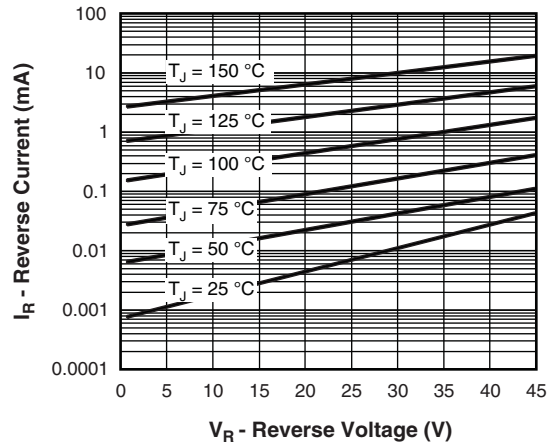


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

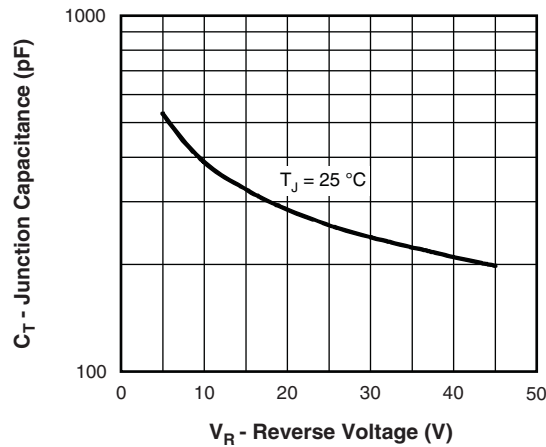


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

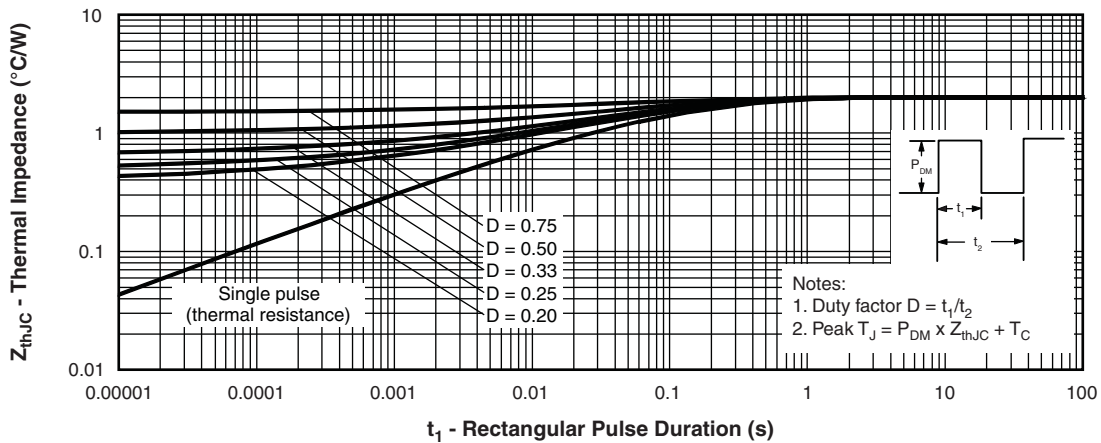


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

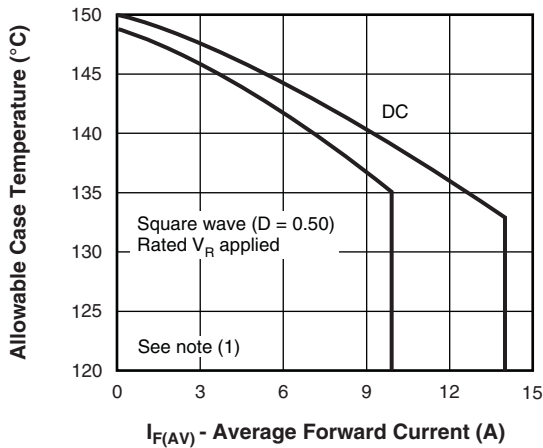


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

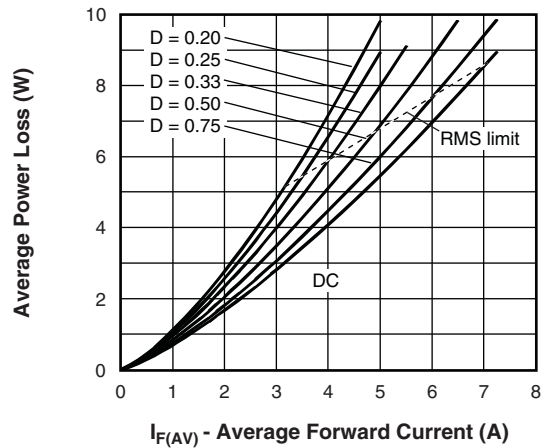


Fig. 6 - Forward Power Loss Characteristics

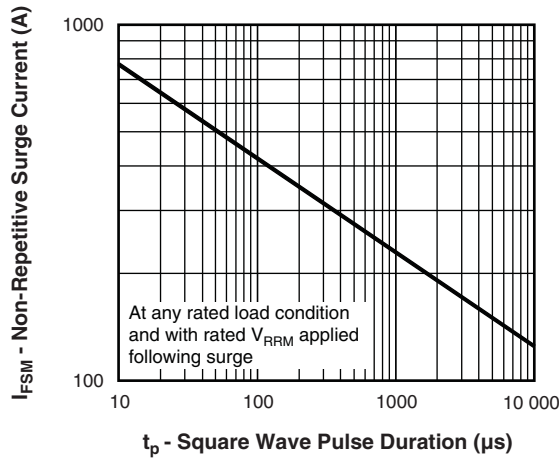


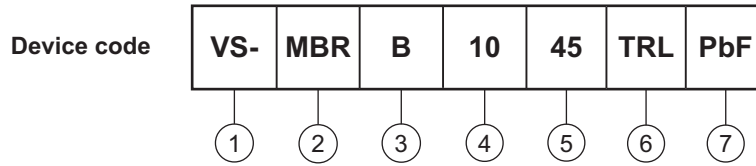
Fig. 7 - Maximum Non-Repetitive Surge Current

**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;
- $P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);
- $P_{d_{REV}}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = Rated  $V_R$



## ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Essential part number
- 3** - B = surface mount
- 4** - Current rating (10 = 10 A)
- 5** - Voltage ratings 35 = 35 V  
45 = 45 V
- 6** -
  - None = tube (50 pieces)
  - TRL = tape and reel (left oriented)
  - TRR = tape and reel (right oriented)
- 7** - PbF = lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95046">www.vishay.com/doc?95046</a>
Part marking information	<a href="http://www.vishay.com/doc?95054">www.vishay.com/doc?95054</a>
Packaging information	<a href="http://www.vishay.com/doc?95032">www.vishay.com/doc?95032</a>
SPIICE model	<a href="http://www.vishay.com/doc?95293">www.vishay.com/doc?95293</a>

## D<sup>2</sup>PAK

### DIMENSIONS in millimeters and inches

Conforms to JEDEC® outline D<sup>2</sup>PAK (SMD-220)



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	e	2.54 BSC		0.100 BSC		
b2	1.14	1.78	0.045	0.070		H	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
c	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25 BSC		0.010 BSC		
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

#### Notes

- Dimensioning and tolerancing per ASME Y14.5 M-1994
- Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- Thermal pad contour optional within dimension E, L1, D1 and E1
- Dimension b1 and c1 apply to base metal only
- Datum A and B to be determined at datum plane H
- Controlling dimension: inch
- Outline conforms to JEDEC® outline TO-263AB



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